Product Preview 200 mA, Low V_{IN}, Low **Noise and High PSRR LDO Regulator**

The NCP110 is a linear regulator capable of supplying 200 mA output current from 1.1 V input voltage. The device provides wide output range from 0.6 V up to 4.0 V, very low noise and high PSRR. Due to low quiescent current the NCP110 is suitable for battery powered devices such as smartphones and tablets. The device is designed to work with a 1 µF input and a 1 µF output ceramic capacitor. It is available in ultra-small 0.35P, 0.65 mm x 0.65 mm Chip Scale Package (CSP) and XDFN4 0.65P, 1 mm x 1 mm.

Features

- Operating Input Voltage Range: 1.1 V to 5.5 V
- Available in Fixed Voltage Option: 0.6 V to 4.0 V
- ±2% Accuracy Over Load/Temperature
- Ultra Low Quiescent Current Typ. 18 μA
- Standby Current: Typ. 0.1 µA
- Very Low Dropout: 70 mV for 1.05 V @ 100 mA
- High PSRR: Typ. 95 dB at 20 mA, f = 1 kHz
- Ultra Low Noise: 8.8 µV_{RMS}
- Stable with a 1 µF Small Case Size Ceramic Capacitors
- Available in -WLCSP4 0.65mm x 0.65mm x 0.33mm Case 567JZ -XDFN4 1mm x 1mm x 0.4mm - Case 711AJ
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Battery-powered Equipment
- Wireless LAN Devices
- Smartphones, Tablets
- Cameras, DVRs, STB and Camcorders

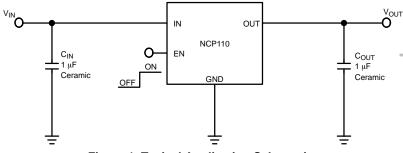
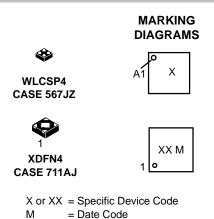


Figure 1. Typical Application Schematics

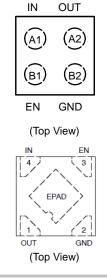
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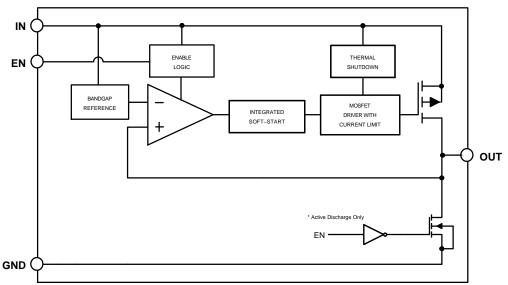


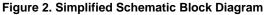


ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 4 of this data sheet.

This document contains information on a product under development. ON Semiconductor reserves the right to change or discontinue this product without notice.





PIN FUNCTION DESCRIPTION

Pin No. CSP4	Pin No. XDFN4	Pin Name	Description
A1	4	IN	Input voltage supply pin
A2	1	OUT	Regulated output voltage. The output should be bypassed with small 1 μF ceramic capacitor.
B1	3	EN	Chip enable: Applying V _{EN} < 0.2 V disables the regulator, Pulling V _{EN} > 0.7 V enables the LDO.
B2	2	GND	Common ground connection
-	EPAD	EPAD	Expose pad can be tied to ground plane for better power dissipation

ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Input Voltage (Note 1)		–0.3 V to 6	V
Output Voltage	V _{OUT}	–0.3 to V _{IN} + 0.3, max. 6 V	V
Chip Enable Input		–0.3 to V _{IN} + 0.3, max. 6 V	V
Output Short Circuit Duration		unlimited	S
Maximum Junction Temperature		150	°C
Storage Temperature		-55 to 150	°C
ESD Capability, Human Body Model (Note 2)		2000	V
ESD Capability, Machine Model (Note 2)	ESD _{MM}	200	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. Refer to ELECTRICAL CHARACTERISTICS and APPLICATION INFORMATION for Safe Operating Area.

2. This device series incorporates ESD protection and is tested by the following methods:

ESD Human Body Model tested per EIA/JESD22-A114

ESD Machine Model tested per EIA/JESD22-A115

Latchup Current Maximum Rating tested per JEDEC standard: JESD78.

THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit	
Thermal Characteristics, CSP4 (Note 3) Thermal Resistance, Junction-to-Air		108	°C/W	
Thermal Characteristics, XDFN4 (Note 3) Thermal Resistance, Junction-to-Air		198.1		

3. Measured according to JEDEC board specification. Detailed description of the board can be found in JESD51-7

Parameter	Parameter Test Conditions		Symbol	Min	Тур	Max	Unit	
Operating Input Voltage		V _{IN}	1.1		5.5	V		
Output Voltage Accuracy	$V_{IN} = V_{OUT(NOM)} + 0.3 V$ ($V_{IN} \ge 1.1 V$)	$V_{OUT(NOM)} \le 1.5 \text{ V}$	V _{OUT}	-30		+30	mV	
	(V _{IN} ≥ 1.1 V)	V _{OUT(NOM) >} 1.5 V		-2		+2	%	
Line Regulation	$V_{OUT(NOM)}$ + 0.5 V \leq V _{IN} \leq	5.5 V, (V _{IN} ≥ 1.1 V)	Line _{Reg}		0.02		%/V	
Load Regulation	I _{OUT} = 1 mA to 2	200 mA	Load _{Reg}		0.001		%/mA	
Dropout Voltage (Note 5)	V _{OUT(NOM)} = 1.05 V	I _{OUT} = 50 mA	V _{DO}		40	70	mV	
		I _{OUT} = 100 mA			70	130		
	V _{OUT(NOM)} = 1.20 V	I _{OUT} = 110 mA			60	140		
		I _{OUT} = 200 mA			110	190		
Output Current Limit	V _{OUT} = 90% V _O	UT(NOM)	I _{CL}	225	300			
Short Circuit Current	V _{OUT} = 0	V _{OUT} = 0 V			300		mA	
Quiescent Current	I _{OUT} = 0 m	I _{OUT} = 0 mA			20	25	μΑ	
Shutdown Current	$V_{EN} \le 0.2$ V, V_{IN} = 1.1 V		I _{DIS}		0.01	1.0	μΑ	
EN Pin Threshold Voltage	EN Input Volta	V _{ENH}	0.7			- V		
	EN Input Volta	V _{ENL}			0.2			
EN Pull Down Current	V _{EN} = 1.1	V	I _{EN}		0.2	0.5	μΑ	
Turn–On Time	C_{OUT} = 1 µF, From asse V _{OUT} = 95% V _O		t _{ON}		120		μS	
Power Supply Rejection Ratio	I _{OUT} = 20 mA, V _{IN} = V _{OUT} + 0.3 V	f = 100 Hz f = 1 kHz f = 10 kHz f = 100 kHz	PSRR		90 95 85 55		dB	
Output Voltage Noise	f = 10 Hz to 10	f = 10 Hz to 100 kHz			8.8		μV_{RMS}	
Thermal Shutdown Threshold	Temperature	T _{SDH}		160		°C		
	Temperature 1	T _{SDL}		140		°C		
Active Output Discharge Resis- tance	V _{EN} < 0.2 V, Vers	ion A only	R _{DIS}		280		Ω	

ELECTRICAL CHARACTERISTICS $-40^{\circ}C \le T_J \le 125^{\circ}C$; $V_{IN} = V_{OUT(NOM)} + 0.3$ V or 1.1 V, whichever is greater; $I_{OUT} = 1$ mA, $C_{IN} = 1$ mA,	
$C_{OUT} = 1 \ \mu F$, unless otherwise noted. $V_{EN} = 1.0 \ V$. Typical values are at $T_{J} = +25^{\circ}C$ (Note 4).	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
Performance guaranteed over the indicated operating temperature range by design and/or characterization. Production tested at T_A = 25°C. Low duty cycle pulse techniques are used during the testing to maintain the junction temperature as close to ambient as possible.
Dropout voltage is characterized when V_{OUT} falls 0.02 x V_{OUT(NOM)} below V_{OUT(NOM)}.

6. Guaranteed by design.

ORDERING INFORMATION

Device	Nominal Output Voltage	Marking	Description	Rotation	Package	Shipping [†]
NCP110AFCT060T2G	0.60 V	С		0°		
NCP110AFCT105T2G	1.05 V	А	200 mA, Active Discharge	0°	WLCSP4 CASE 567JZ	5000 / Tape &
NCP110AFCT120T2G	1.20 V	F	200 IIIA, Active Discharge	0°	(Pb-Free)	Reel
NCP110AFCT180T2G	1.80 V	D		0°		

ORDERING INFORMATION

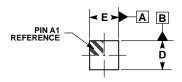
Device	Nominal Output Voltage	Marking	Description	Package	Shipping
NCP110AMX060TBG	0.60 V	FC			
NCP110AMX105TBG	1.05 V	FA			3000 /
NCP110AMX120TBG	1.20 V	FF	200 mA, Active Discharge	XDFN4 (Pb-Free)	Tape &
NCP110AMX180TBG	1.80 V	FD			Reel
NCP110AMX280TBG	2.80 V	FE			

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

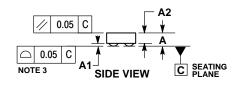
PACKAGE DIMENSIONS

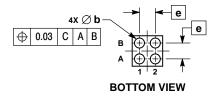
WLCSP4, 0.64x0.64 CASE 567JZ

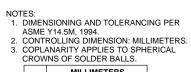
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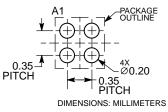






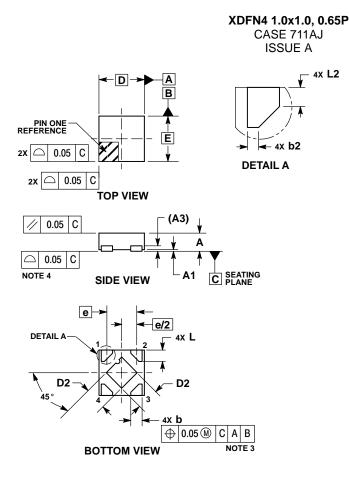
	ROWINS OF SOLDER BALLS.					
	MILLIMETERS					
DIM	MIN	MAX				
Α			0.33			
A1	0.04 0.06 0.08					
A2	0.23 REF					
b	0.195	0.210	0.225			
D	0.610	0.640	0.670			
Е	0.610	0.640	0.670			
е	0.35 BSC					

RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

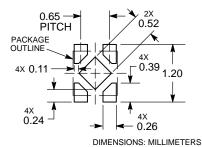


NOTES

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- 0.20 mm FROM THE TERMINAL TIPS. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

	MILLIMETERS		
DIM	MIN	MAX	
Α	0.33	0.43	
A1	0.00	0.05	
A3	0.10	REF	
b	0.15	0.25	
b2	0.02	0.12	
D	1.00 BSC		
D2	0.43	0.53	
Е	1.00	BSC	
е	0.65 BSC		
L	0.20	0.30	
L2	0.07	0.17	

RECOMMENDED **MOUNTING FOOTPRINT***



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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